



60V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on)}	I _D T _A = +25°C
-60V	390 m $Ω @ V_{GS} = -10$ V	-2.3A
-00 <i>V</i>	595mΩ @ V _{GS} = -4.5V	-1.9A

Description and Applications

This MOSFET is designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor Control
- DC-DC Converters
- Power Management Functions
- Uninterrupted Power Supply

Features and Benefits

- Fast Switching Speed
- Low Gate Drive
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

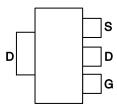
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe;
 Solderable per MIL-STD-202, Method 208 [®]
- Weight: 0.112 grams (Approximate)

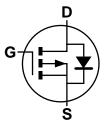
SOT223



Top View



Pin Out - Top View



Equivalent Circuit

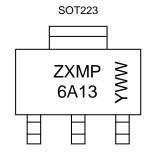
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXMP6A13GTA	ZXMP6A13	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http:// www.diodes.com/products/packages.html.

Marking Information



ZXMP 6A13 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)



Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V_{DSS}	-60	V
Gate-Source Voltage			V _{GS}	±20	V
		(Note 6)		-2.3	
Continuous Drain Current	$V_{GS} = 10V$	$T_A = +70^{\circ}C \text{ (Note 6)}$	I _D	-1.9	Α
		(Note 5)		-1.7	
Pulsed Drain Current	V _{GS} = 10V	(Note 7)	I _{DM}	-7.8	Α
Continuous Source Current (Body Diode) (Note 6)		Is	-4.1	Α	
Pulsed Source Current (Body Diode) (Note 7)		I _{SM}	-7.8	Α	

Thermal Characteristics ($@T_A = +25^{\circ}C$ unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)		2.0 16	W mW/°C	
Linear Derating Factor	(Note 6)	P _D	3.9 31		
Thermal Desigtance Junction to Ambient	(Note 5)		62.5		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	32.0	°C/W	
Thermal Resistance, Junction to Lead	(Note 8)	$R_{ heta JL}$	9.8		
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to 150	°C	

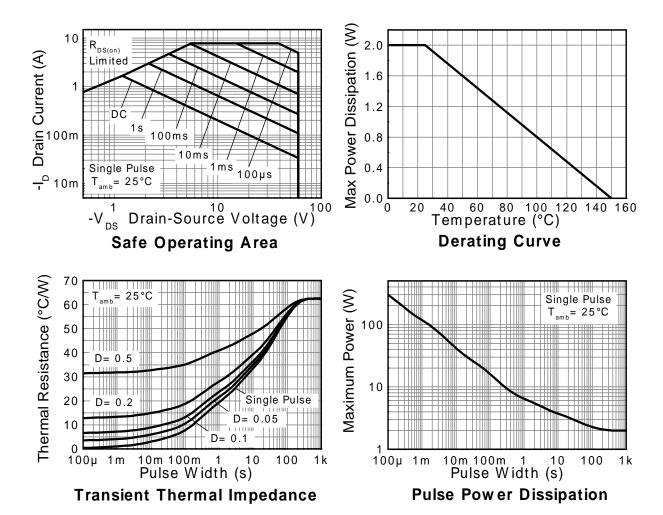
Notes:

- 5. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 6. Same as Note 5, except the device is measured at $t \le 10$ sec.
- 7. Same as Note 5, except the device is pulsed with D = 0.02 and pulse width 300μs. The pulse current is limited by the maximum junction temperature.

 8. Thermal resistance from junction to solder-point (at the end of the drain lead).



Thermal Characteristics





Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

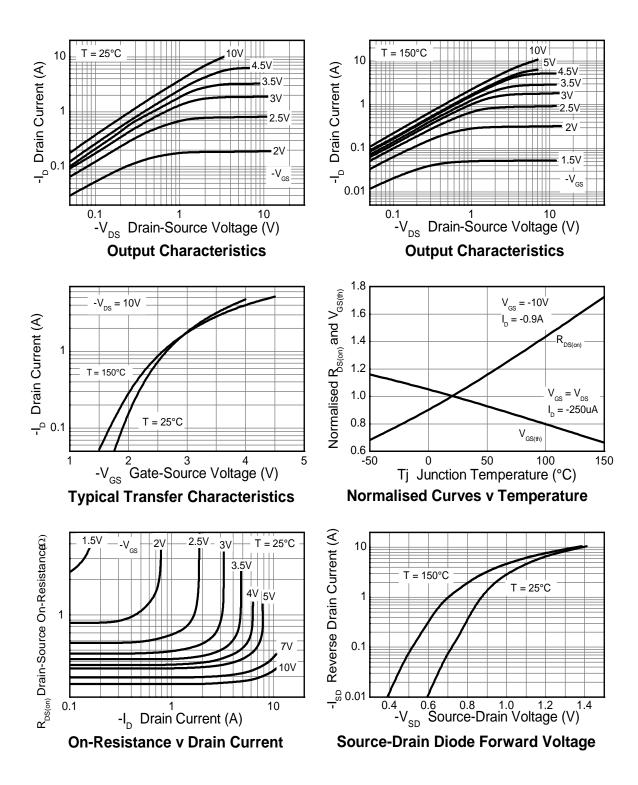
Characteristic	Symbol	Min	Тур	Max	Unit	Test Co	ondition
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV _{DSS}	-60	_	_	V	$I_D = -250 \mu A, V_{GS}$	= 0V
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-0.5	μΑ	$V_{DS} = -60V, V_{GS}$	= 0V
Gate-Source Leakage	I _{GSS}		_	±100	nA	$V_{GS} = \pm 20V, V_{DS}$	= 0V
ON CHARACTERISTICS							
Gate Threshold Voltage	$V_{GS(th)}$	-1.0		-3.0	V	$I_D = -250 \mu A, V_{DS}$	= V _{GS}
Static Drain Source On Decistones (Note 0)				0.390	Ω	$V_{GS} = -10V, I_{D} =$	-0.9A
Static Drain-Source On-Resistance (Note 9)	R _{DS} (ON)	_	_	0.595	77	$V_{GS} = -4.5V, I_{D} =$	-0.8A
Forward Transconductance (Notes 9 & 10)	9 _{fs}	_	1.8	_	S	$V_{DS} = -15V, I_{D} =$	-0.9A
Diode Forward Voltage (Note 9)	V_{SD}	_	-0.85	-0.95	V	I _S = -0.8A, V _{GS} =	$0V, T_J = +25^{\circ}C$
Reverse Recovery Time (Note 10)	t _{rr}		21.1	_	ns	$I_S = -0.9A$, di/dt =	: 100A/µs,
Reverse Recovery Charge (Note 10)	Qrr	_	19.3	_	nC	T _J = +25°C	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C _{iss}	_	219	_	pF	V _{DS} = -30V, V _{GS} = 0V f = 1MHz	
Output Capacitance	Coss	_	25.7		pF		
Reverse Transfer Capacitance	C _{rss}	_	20.5	_	pF] = 11VII 12	
Total Gate Charge (Note 11)	Qg	_	2.9	_	nC	$V_{GS} = -4.5V$	
Total Gate Charge (Note 11)	Qg		5.9	_	nC		$V_{DS} = -30V$
Gate-Source Charge (Note 11)	Q _{gs}	_	0.74	_	nC	$V_{GS} = -10V$	$I_D = -0.9A$
Gate-Drain Charge (Note 11)	Q_{gd}		1.5	_	nC	1	
Turn-On Delay Time (Note 11)	t _{D(on)}	_	1.6	_	ns		
Turn-On Rise Time (Note 11)	tr	_	2.2	_	ns	$V_{DD} = -30V, V_{GS} = -10V$ $I_{D} = -1A, R_{G} \cong 6.0\Omega$	
Turn-Off Delay Time (Note 11)	t _{D(off)}	_	11.2	_	ns		
Turn-Off Fall Time (Note 11)	t _f	_	5.7	_	ns		

Notes:

^{9.} Measured under pulsed conditions. Pulse width $\leq 300\mu s$; duty cycle $\leq 2\%$ 10. For design aid only, not subject to production testing. 11. Switching characteristics are independent of operating junction temperatures.

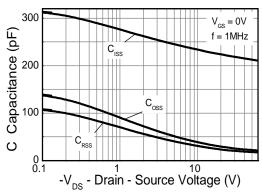


Typical Characteristics

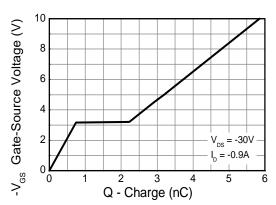




Typical Characteristics (cont.)

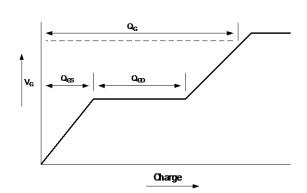


Capacitance v Drain-Source Voltage

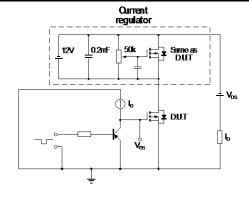


Gate-Source Voltage v Gate Charge

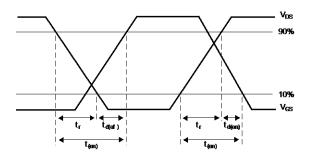
Test Circuits



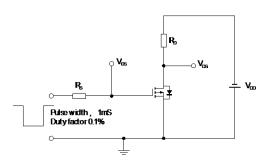
Basic gate charge waveform



Gate charge test circuit



Switching time waveforms

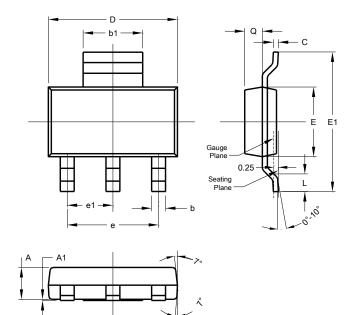


Switching time test circuit



Package Outline Dimensions

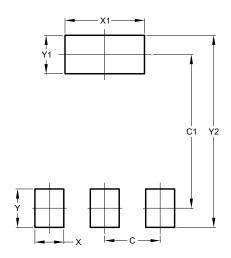
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
ø	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	2.30		
C1	6.40		
Х	1.20		
X1	3.30		
Υ	1.60		
Y1	1.60		
V2	8 00		



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